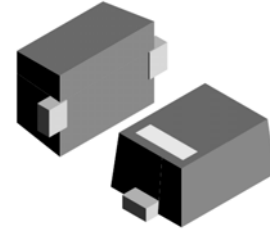


Features

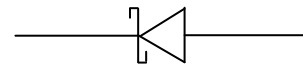
- SOD-923 Package
- Low forward voltage
- Forward current: 0.5A
- Reverse Voltage 30V
- MSL: Level 1 – unlimited



SOD-923

Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Low voltage rectification
- High efficiency DC-to-DC conversion
- Low power consumption applications



Schematic Diagram

Description

Planar Maximum Efficiency General Application (MEGA) schottky barrier diode with an integrated guard ring for stress protection encapsulated in a SOD-923 small package.

Absolute Maximum Ratings

($T_A=25^{\circ}\text{C}$ unless otherwise specified)

| Parameter | Symbol | Condition | Min | Max | Unit |
|-------------------------------------|-----------------|---|-----|------|--------------------|
| Continuous reverse voltage | V_{RRM} | | | 30 | V |
| Repetitive peak forward current | I_{FRM} | $t_p \leq 1\text{ms}, \delta \leq 0.25$ | | 2.5 | A |
| Continuous forward current | I_F | | | 0.5 | A |
| Non-repetitive peak forward current | I_{FSM} | $t=8\text{ms}, \text{square wave}$ | | 3.0 | A |
| Junction temperature | T_J | | | 150 | $^{\circ}\text{C}$ |
| Operating ambient temperature | $T_{AMB}^{(1)}$ | | -65 | +150 | $^{\circ}\text{C}$ |
| Storage temperature | $T_{STG}^{(1)}$ | | -65 | +150 | $^{\circ}\text{C}$ |

Notes:

1. For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_F(AV)$ rating will be available on request.

Electrical Characteristics

($T_A=25^\circ\text{C}$ unless otherwise specified)

| Parameter | Symbol | Condition | Typ | Max | Unit |
|----------------------------|--------|--------------------------------|-----|-----|---------------|
| Continuous forward voltage | V_F | $I_F=10\text{mA}$ | 90 | 300 | mV |
| | | $I_F=100\text{mA}$ | 380 | 420 | mV |
| | | $I_F=200\text{mA}$ | 420 | 500 | mV |
| | | $I_F=500\text{mA}$ | 500 | 650 | mV |
| Continuous reverse current | I_R | $V_R=10\text{V}$ | 2 | 200 | μA |
| | | $V_R=30\text{V}$ | 10 | 500 | μA |
| Diode capacitance | C_d | $V_R=1\text{V}; f=1\text{MHz}$ | 24 | | pF |

Pulse test: $t_p \leq 300\mu\text{s}$; $\delta \leq 0.02$

Typical Characteristic Curves

Fig.1 Forward current as a function of forward Voltage; typical values

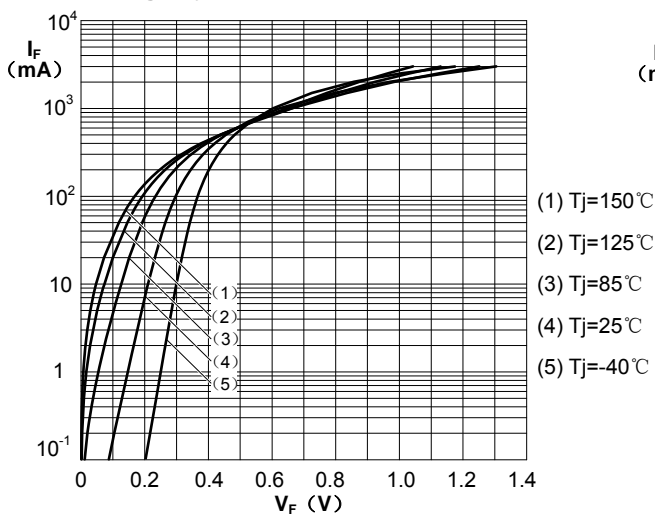


Fig.2 Reverse current as a function of reverse voltage; typical values

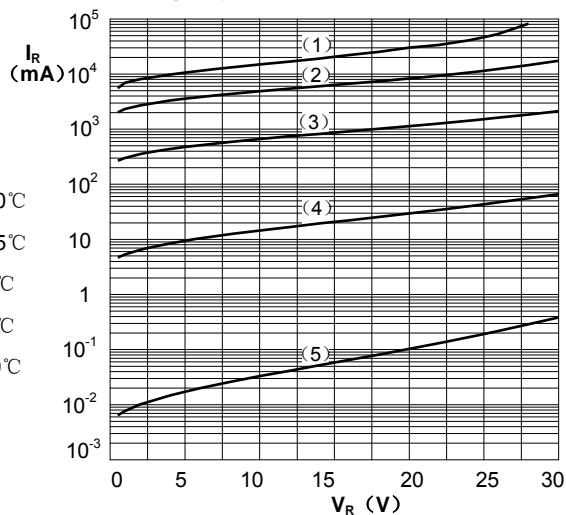
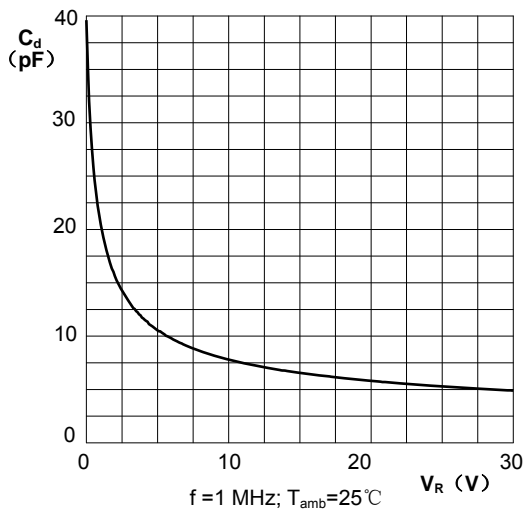
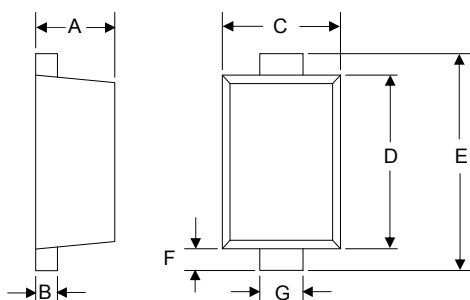


Fig.3 Diode capacitance as a function of reverse Voltage; typical values

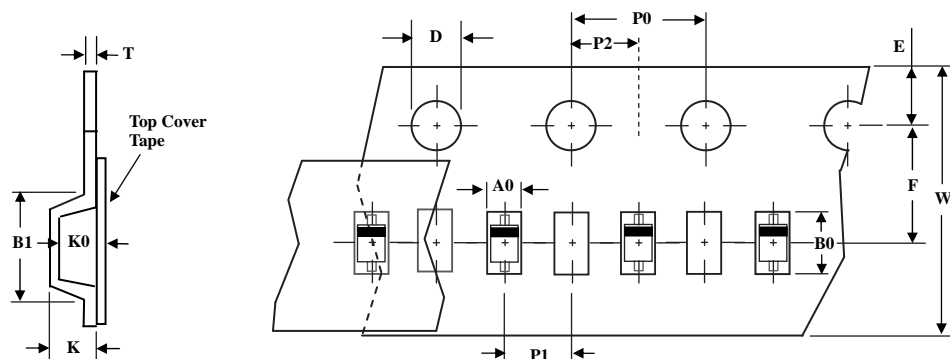


Product Dimensions



| Dim | Millimeters | |
|-----|-------------|------|
| | min | max |
| A | 0.36 | 0.43 |
| B | 0.07 | 0.17 |
| C | 0.55 | 0.65 |
| D | 0.75 | 0.85 |
| E | 0.95 | 1.05 |
| F | 0.05 | 0.15 |
| G | 0.15 | 0.25 |

Package Information



| TapeSize(W) | B1 max | D | E | F | K max | P0 | P1 | P2 | T max | W max |
|-------------|--------|-----------|----------|----------|-------|---------|----------|----------|-------|-------|
| 8 | 4.55 | 1.55±0.05 | 1.75±0.1 | 3.5±0.05 | 2.4 | 4.0±0.1 | 2.0±0.05 | 2.0±0.05 | 0.6 | 8.3 |

Note:1. Unit : mm

2. A0, B0, and K0 are determined by component size. The clearance between the components and the cavity must be within 0.05mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity.

Marking

